

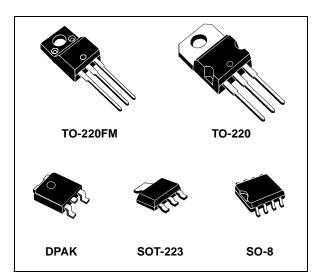
LD1117 SERIES

LOW DROP FIXED AND ADJUSTABLE POSITIVE VOLTAGE REGULATORS

- LOW DROPOUT VOLTAGE (1V TYP.)
- 2.85V DEVICE PERFORMANCES ARE SUITABLE FOR SCSI-2 ACTIVE TERMINATION
- OUTPUT CURRENT UP TO 800 mA
- FIXED OUTPUT VOLTAGE OF: 1.2V, 1.8V, 2.5V, 2.85V, 3.0V, 3.3V, 5.0V
- ADJUSTABLE VERSION AVAILABILITY (V_{rel}=1.25V)
- INTERNAL CURRENT AND THERMAL LIMIT
- AVAILABLE IN ± 1% (AT 25°C) AND 2% IN FULL TEMPERATURE RANGE
- SUPPLY VOLTAGE REJECTION: 75dB (TYP.)

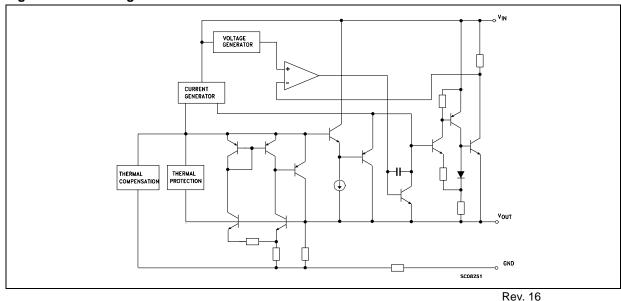
DESCRIPTION

The LD1117 is a LOW DROP Voltage Regulator able to provide up to 800mA of Output Current, available even in adjustable version (Vref=1.25V). Concerning fixed versions, are offered the following Output Voltages: 1.2V,1.8V,2.5V,2.85V, 3.0V 3.3V and 5.0V. The 2.85V type is ideal for SCSI-2 lines active termination. The device is supplied in: SOT-223, DPAK, SO-8, TO-220 and TO-220FM. The SOT-223 and DPAK surface mount packages optimize the thermal characteristics even offering a relevant space saving effect. High efficiency is assured by NPN



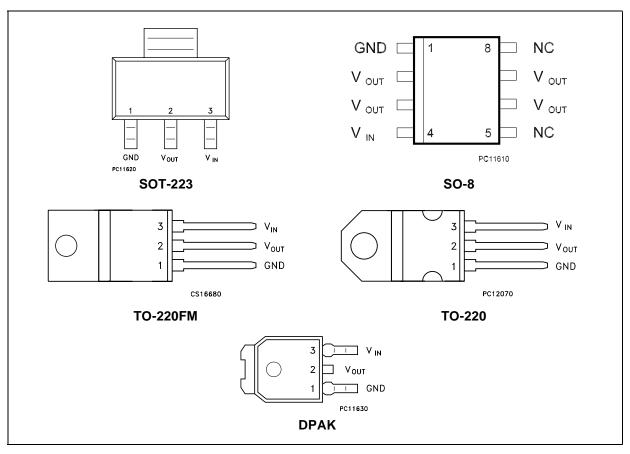
pass transistor. In fact in this case, unlike than PNP one, the Quiescent Current flows mostly into the load. Only a very common $10\mu\text{F}$ minimum capacitor is needed for stability. On chip trimming allows the regulator to reach a very tight output voltage tolerance, within \pm 1% at 25°C. The ADJUSTABLE LD1117 is pin to pin compatible with the other standard. Adjustable voltage regulators maintaining the better performances in terms of Drop and Tolerance.

Figure 1: Block Diagram



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Figure 2: Pin Connection (top view)



NOTE: The TAB is connected to the $V_{\mbox{\scriptsize OUT}}$.

Table 1: Order Codes

SOT-223	SO-8	DPAK	TO-220	TO-220FM	OUTPUT VOLTAGE
LD1117S12	LD1117D12 (*)	LD1117DT12	LD1117V12 (*)	LD1117F12 (*)	1.2 V
LD1117S12C (*)	LD1117D12C (*)	LD1117DT12C	LD1117V12C (*)	LD1117F12C (*)	1.2 V
LD1117S18	LD1117D18	LD1117DT18	LD1117V18	LD1117F18	1.8 V
LD1117S18C	LD1117D18C	LD1117DT18C	LD1117V18C	LD1117F18C	1.8 V
LD1117S25	LD1117D25	LD1117DT25	LD1117V25	LD1117F25	2.5 V
LD1117S25C	LD1117D25C	LD1117DT25C	LD1117V25C	LD1117F25C	2.5 V
LD1117S28	LD1117D28	LD1117DT28	LD1117V28	LD1117F28	2.85 V
LD1117S30	LD1117D30	LD1117DT30	LD1117V30	LD1117F30	3 V
LD1117S30C	LD1117D30C	LD1117DT30C	LD1117V30C	LD1117F30C	3 V
LD1117S33	LD1117D33	LD1117DT33	LD1117V33	LD1117F33	3.3 V
LD1117S33C	LD1117D33C	LD1117DT33C	LD1117V33C	LD1117F33C	3.3 V
LD1117S50	LD1117D50	LD1117DT50	LD1117V50	LD1117F50	5 V
LD1117S50C	LD1117D50C	LD1117DT50C	LD1117V50C	LD1117F50C	5 V
LD1117S	LD1117D	LD1117DT	LD1117V	LD1117F	ADJ FROM 1.25 TO 15V
LD1117SC	LD1117DC	LD1117DTC	LD1117VC	LD1117FC	ADJ FROM 1.25 TO 15V

(*) Available on request

Table 2: Absolute Maximum Ratings

Symbol	Parameter	Parameter		
V _{IN}	DC Input Voltage	15	V	
P _{tot}	Power Dissipation	12	W	
T _{stg}	Storage Temperature Range		-40 to +150	°C
T _{op}	Operating Junction Temperature Range	for C Version	-40 to +125	°C
		for standard Version	0 to +125	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied. Over the above suggested Max Power Dissipation a Short Circuit could definitively damage the device.

Table 3: Thermal Data

Symbol	Parameter	SOT-223	SO-8	DPAK	TO-220	TO-220FM	Unit
R _{thj-case}	Thermal Resistance Junction-case	15	20	8	3	4	°C/W
R _{thj-amb}	Thermal Resistance Junction-ambient				50	60	°C/W

Figure 3: Application Circuit (FOR 1.2 V)

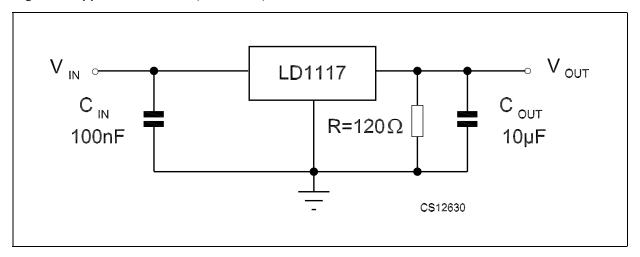


Figure 4: Application Circuit (FOR OTHER FIXED OUTPUT VOLTAGES)

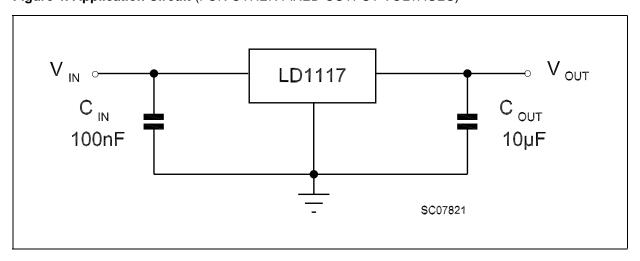


Table 4: Electrical Characteristics Of LD1117#12 (refer to the test circuits, T_J = 0 to 125°C, C_O = 10 μ F, R = 120 Ω between GND and OUT pins, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 3.2 \text{ V } I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	1.188	1.20	1.212	V
Vo	Reference Voltage	$I_O = 10 \text{ to } 800 \text{ mA}$ $V_{in} - V_O = 1.4 \text{ to } 10 \text{ V}$	1.140	1.20	1.260	V
ΔV_{O}	Line Regulation	$V_{in} - V_{O} = 1.5 \text{ to } 13.75 \text{ V}$ $I_{O} = 10 \text{ mA}$		0.035	0.2	%
ΔV_{O}	Load Regulation	$V_{in} - V_{O} = 3 \text{ V}$ $I_{O} = 10 \text{ to } 800 \text{ mA}$		0.1	0.4	%
ΔV_{O}	Temperature Stability			0.5		%
ΔV_{O}	Long Term Stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating Input Voltage				15	V
I _{adj}	Adjustment Pin Current	V _{in} ≤ 15 V		60	120	μA
Δl_{adj}	Adjustment Pin Current Change	$V_{in} - V_{O} = 1.4 \text{ to } 10 \text{ V}$ $I_{O} = 10 \text{ to } 800 \text{ mA}$		1	5	μA
I _{O(min)}	Minimum Load Current	V _{in} = 15 V		2	5	mA
I _O	Output Current	$V_{in} - V_O = 5 V$ $T_J = 25$ °C	800	950	1300	mA
eN	Output Noise (%V _O)	B = 10Hz to 10KHz $T_J = 25$ °C		0.003		%
SVR	Supply Voltage Rejection	I_O = 40 mA f = 120Hz T_J = 25°C V_{in} - V_O = 3 V V_{ripple} = 1 V_{PP}	60	75		dB
V _d	Dropout Voltage	I _O = 100 mA		1	1.1	V
		I _O = 500 mA		1.05	1.15	
		I _O = 800 mA		1.10	1.2	
	Thermal Regulation	T _a = 25°C 30ms Pulse		0.01	0.1	%/W

Table 5: Electrical Characteristics Of LD1117#18 (refer to the test circuits, T_J = 0 to 125°C, C_O = 10 μF unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 3.8 \text{ V } I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	1.78	1.8	1.82	V
Vo	Output Voltage	$I_{O} = 0 \text{ to } 800 \text{ mA}$ $V_{in} = 3.3 \text{ to } 8 \text{ V}$	1.76		1.84	V
ΔV_{O}	Line Regulation	$V_{in} = 3.3 \text{ to } 8 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	6	mV
ΔV_{O}	Load Regulation	$V_{in} = 3.3 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	10	mV
ΔV_{O}	Temperature Stability			0.5		%
ΔV_{O}	Long Term Stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating Input Voltage	I _O = 100 mA			10	V
I _d	Quiescent Current	$V_{in} \le 8 \text{ V}$		5	10	mA
Io	Output Current	V _{in} = 6.8 V T _J = 25°C	800	950	1300	mA
eN	Output Noise Voltage	B =10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	I_{O} = 40 mA f = 120Hz T_{J} = 25°C V_{in} = 5.5 V V_{ripple} = 1 V_{PP}	60	75		dB
V _d	Dropout Voltage	I _O = 100 mA		1	1.1	V
		I _O = 500 mA		1.05	1.15	
		I _O = 800 mA		1.10	1.2	
	Thermal Regulation	T _a = 25°C 30ms Pulse		0.01	0.1	%/W

Table 6: Electrical Characteristics Of LD1117#25 (refer to the test circuits, $T_J = 0$ to 125°C, $C_O = 10~\mu F$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 4.5 \text{ V } I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	2.475	2.5	2.525	V
Vo	Output Voltage	$I_{O} = 0 \text{ to } 800 \text{ mA}$ $V_{in} = 3.9 \text{ to } 10 \text{ V}$	2.45		2.55	V
ΔV_{O}	Line Regulation	$V_{in} = 3.9 \text{ to } 10 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	6	mV
ΔV_{O}	Load Regulation	V _{in} = 3.9 V I _O = 0 to 800 mA		1	10	mV
ΔV_{O}	Temperature Stability			0.5		%
ΔV_{O}	Long Term Stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating Input Voltage	I _O = 100 mA			15	V
I _d	Quiescent Current	V _{in} ≤ 10 V		5	10	mA
Io	Output Current	V _{in} = 7.5 V T _J = 25°C	800	950	1300	mA
eN	Output Noise Voltage	B =10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_{O} = 40 \text{ mA f} = 120 \text{Hz}$ $T_{J} = 25 ^{\circ}\text{C}$ $V_{in} = 5.5 \text{ V}$ $V_{ripple} = 1 \text{ V}_{PP}$	60	75		dB
V _d	Dropout Voltage	I _O = 100 mA		1	1.1	V
		I _O = 500 mA		1.05	1.15	
		I _O = 800 mA		1.10	1.2	
	Thermal Regulation	T _a = 25°C 30ms Pulse		0.01	0.1	%/W

Table 7: Electrical Characteristics Of LD1117#28 (refer to the test circuits, T_J = 0 to 125°C, C_O = 10 μF unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 4.85 \text{ VI}_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	2.82	2.85	2.88	V
Vo	Output Voltage	$I_{O} = 0$ to 800 mA $V_{in} = 4.25$ to 10 V	2.79		2.91	V
ΔV_{O}	Line Regulation	V _{in} = 4.25 to 10 V I _O = 0 mA		1	6	mV
ΔV_{O}	Load Regulation	$V_{in} = 4.25 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	10	mV
ΔV_{O}	Temperature Stability			0.5		%
ΔV_{O}	Long Term Stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating Input Voltage	I _O = 100 mA			15	V
I _d	Quiescent Current	V _{in} ≤ 10 V		5	10	mA
Io	Output Current	V _{in} = 7.85 VT _J = 25°C	800	950	1300	mA
eN	Output Noise Voltage	B =10Hz to 10KHz T _J = 25°C		100		μV
SVR	Supply Voltage Rejection	I_O = 40 mA f = 120Hz T_J = 25°C V_{in} = 5.85 VV _{ripple} = 1 V _{PP}	60	75		dB
V _d	Dropout Voltage	I _O = 100 mA		1	1.1	V
		I _O = 500 mA		1.05	1.15	
		I _O = 800 mA		1.10	1.2	
	Thermal Regulation	T _a = 25°C 30ms Pulse		0.01	0.1	%/W

Table 8: Electrical Characteristics Of LD1117#30 (refer to the test circuits, T_J = 0 to 125°C, C_O = 10 μF unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 5 \text{ V}$ $I_O = 10 \text{ mA}$ $T_J = 25^{\circ}\text{C}$	2.97	3	3.03	V
Vo	Output Voltage	$I_{O} = 0 \text{ to } 800 \text{ mA}$ $V_{in} = 4.5 \text{ to } 10 \text{ V}$	2.94		3.06	V
ΔV_{O}	Line Regulation	$V_{in} = 4.5 \text{ to } 12 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	6	mV
ΔV_{O}	Load Regulation	$V_{in} = 4.5 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	10	mV
ΔV_{O}	Temperature Stability			0.5		%
ΔV_{O}	Long Term Stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating Input Voltage	I _O = 100 mA			15	V
I _d	Quiescent Current	V _{in} ≤ 12 V		5	10	mA
Io	Output Current	V _{in} = 8 V T _J = 25°C	800	950	1300	mA
eN	Output Noise Voltage	B = 10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_O = 40 \text{ mA f} = 120 \text{Hz}$ $T_J = 25^{\circ}\text{C}$ $V_{in} = 6 \text{ V}$ $V_{ripple} = 1 \text{ V}_{PP}$	60	75		dB
V _d	Dropout Voltage	I _O = 100 mA		1	1.1	V
		I _O = 500 mA		1.05	1.15	
		I _O = 800 mA		1.10	1.2	
	Thermal Regulation	T _a = 25°C 30ms Pulse		0.01	0.1	%/W

Table 9: Electrical Characteristics Of LD1117#33 (refer to the test circuits, T_J = 0 to 125°C, C_O = 10 μF unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 5.3 \text{ V } I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	3.267	3.3	3.333	V
Vo	Output Voltage	$I_{O} = 0$ to 800 mA $V_{in} = 4.75$ to 10 V	3.235		3.365	V
ΔV_{O}	Line Regulation	$V_{in} = 4.75 \text{ to } 15 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	6	mV
ΔV_{O}	Load Regulation	$V_{in} = 4.75 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	10	mV
ΔV_{O}	Temperature Stability			0.5		%
ΔV_{O}	Long Term Stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating Input Voltage	I _O = 100 mA			15	V
I _d	Quiescent Current	V _{in} ≤ 15 V		5	10	mA
Io	Output Current	V _{in} = 8.3 V T _J = 25°C	800	950	1300	mA
eN	Output Noise Voltage	B =10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_{O} = 40 \text{ mA f} = 120 \text{Hz}$ $T_{J} = 25 ^{\circ}\text{C}$	60	75		dB
		$V_{in} = 6.3 \text{ V } V_{ripple} = 1 \text{ V}_{PP}$				
V_d	Dropout Voltage	I _O = 100 mA		1	1.1	V
		I _O = 500 mA		1.05	1.15	
		I _O = 800 mA		1.10	1.2	
	Thermal Regulation	T _a = 25°C 30ms Pulse		0.01	0.1	%/W

Table 10: Electrical Characteristics Of LD1117#50 (refer to the test circuits, T_J = 0 to 125°C, C_O = 10 μF unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 7 \text{ V}$ $I_O = 10 \text{ mA}$ $T_J = 25^{\circ}\text{C}$	4.95	5	5.05	V
Vo	Output Voltage	$I_{O} = 0 \text{ to } 800 \text{ mA}$ $V_{in} = 6.5 \text{ to } 15 \text{ V}$	4.9		5.1	V
ΔV_{O}	Line Regulation	$V_{in} = 6.5 \text{ to } 15 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	10	mV
ΔV_{O}	Load Regulation	$V_{in} = 6.5 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	15	mV
ΔV_{O}	Temperature Stability			0.5		%
ΔV_{O}	Long Term Stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating Input Voltage	I _O = 100 mA			15	V
I _d	Quiescent Current	V _{in} ≤ 15 V		5	10	mA
I _O	Output Current	V _{in} = 10 V T _J = 25°C	800	950	1300	mA
eN	Output Noise Voltage	B =10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_O = 40 \text{ mA f} = 120 \text{Hz}$ $T_J = 25 ^{\circ}\text{C}$ $V_{in} = 8 \text{ V}$ $V_{ripple} = 1 \text{ V}_{PP}$	60	75		dB
V _d	Dropout Voltage	I _O = 100 mA		1	1.1	V
		I _O = 500 mA		1.05	1.15	
		I _O = 800 mA		1.10	1.2	
	Thermal Regulation	T _a = 25°C 30ms Pulse		0.01	0.1	%/W

Table 11: Electrical Characteristics Of LD1117 (ADJUSTABLE) (refer to the test circuits, $T_J=0$ to 125°C, $C_O=10~\mu F$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{ref}	Reference Voltage	$V_{in} - V_O = 2 V$ $I_O = 10 \text{ mA}$ $T_J = 25^{\circ}\text{C}$	1.238	1.25	1.262	V
V _{ref}	Reference Voltage	$I_O = 10 \text{ to } 800 \text{ mA}$ $V_{in} - V_O = 1.4 \text{ to } 10$ V	1.225		1.275	V
ΔV_{O}	Line Regulation	$V_{in} - V_{O} = 1.5 \text{ to } 13.75 \text{ V}$ $I_{O} = 10 \text{ mA}$		0.035	0.2	%
ΔV_{O}	Load Regulation	$V_{in} - V_{O} = 3 \text{ V}$ $I_{O} = 10 \text{ to } 800 \text{ mA}$		0.1	0.4	%
ΔV_{O}	Temperature Stability			0.5		%
ΔV_{O}	Long Term Stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating Input Voltage				15	V
I _{adj}	Adjustment Pin Current	V _{in} ≤ 15 V		60	120	μA
Δl_{adj}	Adjustment Pin Current Change	$V_{in} - V_{O} = 1.4 \text{ to } 10 \text{ V}$ $I_{O} = 10 \text{ to } 800 \text{ mA}$		1	5	μA
I _{O(min)}	Minimum Load Current	V _{in} = 15 V		2	5	mA
Io	Output Current	$V_{in} - V_O = 5 V$ $T_J = 25$ °C	800	950	1300	mA
eN	Output Noise (%V _O)	B = 10Hz to 10KHz $T_J = 25$ °C		0.003		%
SVR	Supply Voltage Rejection	I_O = 40 mA f = 120Hz T_J = 25°C V_{in} - V_O = 3 V V_{ripple} = 1 V_{PP}	60	75		dB
V _d	Dropout Voltage	I _O = 100 mA		1	1.1	V
		I _O = 500 mA		1.05	1.15	
		I _O = 800 mA		1.10	1.2	
	Thermal Regulation	T _a = 25°C 30ms Pulse		0.01	0.1	%/W

Table 12: Electrical Characteristics Of LD1117#12C (refer to the test circuits, T_J = 0 to 125°C, C_O = 10 μ F, R = 120 Ω between GND and OUT pins, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{ref}	Reference Voltage	$V_{in} - V_{O} = 2V I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	1.176	1.20	1.224	V
V _{ref}	Reference Voltage	$I_O = 10 \text{ to } 800 \text{ mA}$ $V_{in} - V_O = 1.4 \text{ to } 10$ V	1.120	1.20	1.280	V
ΔV_{O}	Line Regulation	$V_{in} - V_{O} = 1.5 \text{ to } 13.75 \text{ V}$ $I_{O} = 10 \text{ mA}$			1	%
ΔV_{O}	Load Regulation	$V_{in} - V_{O} = 3 \text{ V}$ $I_{O} = 10 \text{ to } 800 \text{ mA}$			1	%
ΔV_{O}	Temperature Stability			0.5		%
ΔV_{O}	Long Term Stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating Input Voltage				15	V
I _{adj}	Adjustment Pin Current	V _{in} ≤ 15 V		60	120	μA
ΔI_{adj}	Adjustment Pin Current Change	V _{in} - V _O = 1.4 to 10 V I _O = 10 to 800 mA		1	5	μA
I _{O(min)}	Minimum Load Current	V _{in} = 15 V		2	5	mA
I _O	Output Current	$V_{in} - V_O = 5 V$ $T_J = 25$ °C	800	950	1300	mA
eN	Output Noise (%V _O)	B = 10Hz to 10KHz $T_J = 25$ °C		0.003		%
SVR	Supply Voltage Rejection	I_O = 40 mA f = 120Hz T_J = 25°C V_{in} - V_O = 3 V V_{ripple} = 1 V_{PP}	60	75		dB
V _d	Dropout Voltage	$I_{O} = 100 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1	1.1	V
		$I_{O} = 500 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.05	1.2	
		$I_{O} = 800 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.10	1.3	
	Thermal Regulation	T _a = 25°C 30ms Pulse		0.01	0.1	%/W

Table 13: Electrical Characteristics Of LD1117#18C (refer to the test circuits, T_J = -40 to 125°C, C_O = 10 μF unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 3.8 \text{ V } I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	1.76	1.8	1.84	V
Vo	Output Voltage	$I_{O} = 0 \text{ to } 800 \text{ mA}$ $V_{in} = 3.9 \text{ to } 10 \text{ V}$	1.73		1.87	V
ΔV_{O}	Line Regulation	$V_{in} = 3.3 \text{ to } 8 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	30	mV
ΔV_{O}	Load Regulation	$V_{in} = 3.3 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	30	mV
ΔV_{O}	Temperature Stability			0.5		%
ΔV_{O}	Long Term Stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating Input Voltage	I _O = 100 mA			10	V
I _d	Quiescent Current	$V_{in} \le 8 V$		5	10	mA
I _O	Output Current	V _{in} = 6.8 V T _J = 25°C	800	950	1300	mA
eN	Output Noise Voltage	B = 10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	I_O = 40 mA f = 120Hz T_J = 25°C V_{in} = 5.5 V V_{ripple} = 1 V_{PP}	60	75		dB
V_d	Dropout Voltage	$I_{O} = 100 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1	1.1	V
		I _O = 500 mA T _J = 0 to 125°C		1.05	1.15	
		$I_{O} = 800 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.10	1.2	
V_d	Dropout Voltage	I _O = 100 mA			1.1	V
		I _O = 500 mA			1.2	
		I _O = 800 mA			1.3	
	Thermal Regulation	T _a = 25°C 30ms Pulse		0.01	0.1	%/W

Table 14: Electrical Characteristics Of LD1117#25C (refer to the test circuits, T_J = -40 to 125°C, C_O = 10 μF unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 4.5 \text{ V } I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	2.45	2.5	2.55	V
Vo	Output Voltage	$I_{O} = 0$ to 800 mA $V_{in} = 3.9$ to 10 V	2.4		2.6	V
ΔV_{O}	Line Regulation	$V_{in} = 3.9 \text{ to } 10 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	30	mV
ΔV_{O}	Load Regulation	$V_{in} = 3.9 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	30	mV
ΔV_{O}	Temperature Stability			0.5		%
ΔV_{O}	Long Term Stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating Input Voltage	I _O = 100 mA			15	V
I _d	Quiescent Current	$V_{in} \le 10 \text{ V}$		5	10	mA
Io	Output Current	$V_{in} = 7.5 \text{ V } T_{J} = 25^{\circ}\text{C}$	800	950	1300	mA
eN	Output Noise Voltage	B = 10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_O = 40$ mA f = 120Hz $T_J = 25$ °C $V_{in} = 5.5$ V $V_{ripple} = 1$ V_{PP}	60	75		dB
V_d	Dropout Voltage	$I_{O} = 100 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1	1.1	V
		$I_{O} = 500 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.05	1.15	
		$I_{O} = 800 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.10	1.2	
V_d	Dropout Voltage	I _O = 100 mA			1.1	V
		I _O = 500 mA			1.2	
		I _O = 800 mA			1.3	
	Thermal Regulation	T _a = 25°C 30ms Pulse		0.01	0.1	%/W

Table 15: Electrical Characteristics Of LD1117#30C (refer to the test circuits, T_J = -40 to 125°C, C_O = 10 μF unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 5 \text{ V}$ $I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	2.94	3	3.06	V
Vo	Output Voltage	$I_{O} = 0 \text{ to } 800 \text{ mA}$ $V_{in} = 4.5 \text{ to } 10 \text{ V}$	2.88		3.12	V
ΔV_{O}	Line Regulation	$V_{in} = 4.5 \text{ to } 12 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	30	mV
ΔV_{O}	Load Regulation	$V_{in} = 4.5 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	30	mV
ΔV_{O}	Temperature Stability			0.5		%
ΔV_{O}	Long Term Stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating Input Voltage	I _O = 100 mA			15	V
I _d	Quiescent Current	$V_{in} \le 12 \text{ V}$		5	10	mA
I _O	Output Current	$V_{in} = 8 \text{ V}$ $T_J = 25^{\circ}\text{C}$	800	950	1300	mA
eN	Output Noise Voltage	B =10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_O = 40 \text{ mA f} = 120 \text{Hz}$ $T_J = 25^{\circ}\text{C}$ $V_{in} = 6 \text{ V}$ $V_{ripple} = 1 \text{ V}_{PP}$	60	75		dB
V _d	Dropout Voltage	$I_{O} = 100 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1	1.1	V
		$I_{O} = 500 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.05	1.15	
		$I_{O} = 800 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.10	1.2	
V _d	Dropout Voltage	I _O = 100 mA			1.1	V
		I _O = 500 mA			1.2	
		I _O = 800 mA			1.3	
	Thermal Regulation	T _a = 25°C 30ms Pulse		0.01	0.1	%/W

Table 16: Electrical Characteristics Of LD1117#33C (refer to the test circuits, T_J = -40 to 125°C, C_O = 10 μF unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 5.3 \text{ V } I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	3.24	3.3	3.36	V
Vo	Output Voltage	$I_{O} = 0$ to 800 mA $V_{in} = 4.75$ to 10 V	3.16		3.44	V
ΔV_{O}	Line Regulation	$V_{in} = 4.75 \text{ to } 15 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	30	mV
ΔV_{O}	Load Regulation	$V_{in} = 4.75 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	30	mV
ΔV_{O}	Temperature Stability			0.5		%
ΔV_{O}	Long Term Stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating Input Voltage	I _O = 100 mA			15	V
I _d	Quiescent Current	V _{in} ≤ 15 V		5	10	mA
Io	Output Current	$V_{in} = 8.3 \text{ V } T_{J} = 25^{\circ}\text{C}$	800	950	1300	mA
eN	Output Noise Voltage	B = 10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_O = 40$ mA f = 120Hz $T_J = 25$ °C $V_{in} = 6.3$ V $V_{ripple} = 1$ V_{PP}	60	75		dB
V_d	Dropout Voltage	$I_{O} = 100 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1	1.1	V
		$I_{O} = 500 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.05	1.15	
		$I_{O} = 800 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.10	1.2	
V_d	Dropout Voltage	I _O = 100 mA			1.1	V
		I _O = 500 mA			1.2	
		I _O = 800 mA			1.3	
	Thermal Regulation	T _a = 25°C 30ms Pulse		0.01	0.1	%/W

Table 17: Electrical Characteristics Of LD1117#50C (refer to the test circuits, T_J = -40 to 125°C, C_O = 10 μF unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 7 \text{ V}$ $I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	4.9	5	5.1	V
Vo	Output Voltage	$I_{O} = 0$ to 800 mA $V_{in} = 6.5$ to 15 V	4.8		5.2	V
ΔV_{O}	Line Regulation	V _{in} = 6.5 to 15 V I _O = 0 mA		1	50	mV
ΔV_{O}	Load Regulation	$V_{in} = 6.5 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	50	mV
ΔV_{O}	Temperature Stability			0.5		%
ΔV_{O}	Long Term Stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating Input Voltage	I _O = 100 mA			15	V
I _d	Quiescent Current	V _{in} ≤ 15 V		5	10	mA
I _O	Output Current	V _{in} = 10 V T _J = 25°C	800	950	1300	mA
eN	Output Noise Voltage	B = 10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_O = 40 \text{ mA f} = 120 \text{Hz}$ $T_J = 25 ^{\circ}\text{C}$ $V_{in} = 8 \text{ V}$ $V_{ripple} = 1 \text{ V}_{PP}$	60	75		dB
V _d	Dropout Voltage	$I_{O} = 100 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1	1.1	V
		$I_{O} = 500 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.05	1.15	
		$I_{O} = 800 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.10	1.2	
V _d	Dropout Voltage	I _O = 100 mA			1.1	V
		I _O = 500 mA			1.2	
		I _O = 800 mA			1.3	
	Thermal Regulation	T _a = 25°C 30ms Pulse		0.01	0.1	%/W

Table 18: Electrical Characteristics Of LD1117C (ADJUSTABLE) (refer to the test circuits, T_J = -40 to 125°C, C_O = 10 μF unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V_{ref}	Reference Voltage	$V_{in} - V_{O} = 2 \text{ V}$ $I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	1.225	1.25	1.275	V
V _{ref}	Reference Voltage	$I_O = 10 \text{ to } 800 \text{ mA}$ $V_{in} - V_O = 1.4 \text{ to } 10$ V	1.2		1.3	V
ΔV_{O}	Line Regulation	$V_{in} - V_{O} = 1.5 \text{ to } 13.75 \text{ V}$ $I_{O} = 10 \text{ mA}$			1	%
ΔV_{O}	Load Regulation	$V_{in} - V_{O} = 3 \text{ V}$ $I_{O} = 10 \text{ to } 800 \text{ mA}$			1	%
ΔV_{O}	Temperature Stability			0.5		%
ΔV_{O}	Long Term Stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating Input Voltage				15	V
l _{adj}	Adjustment Pin Current	V _{in} ≤ 15 V		60	120	μA
ΔI_{adj}	Adjustment Pin Current Change	$V_{in} - V_{O} = 1.4 \text{ to } 10 \text{ V}$ $I_{O} = 10 \text{ to } 800 \text{ mA}$		1	10	μA
I _{O(min)}	Minimum Load Current	V _{in} = 15 V		2	5	mA
Io	Output Current	$V_{in} - V_O = 5 V$ $T_J = 25$ °C	800	950	1300	mA
eN	Output Noise (%V _O)	B =10Hz to 10KHz $T_J = 25$ °C		0.003		%
SVR	Supply Voltage Rejection	I_O = 40 mA f = 120Hz T_J = 25°C V_{in} - V_O = 3 V V_{ripple} = 1 V_{PP}	60	75		dB
V _d	Dropout Voltage	$I_{O} = 100 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1	1.1	V
		$I_{O} = 500 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.05	1.15	
		$I_{O} = 800 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.10	1.2	
V _d	Dropout Voltage	I _O = 100 mA			1.1	V
		I _O = 500 mA			1.2	
		I _O = 800 mA			1.3	
	Thermal Regulation	T _a = 25°C 30ms Pulse		0.01	0.1	%/W

TYPICAL APPLICATIONS

Figure 5: Negative Supply

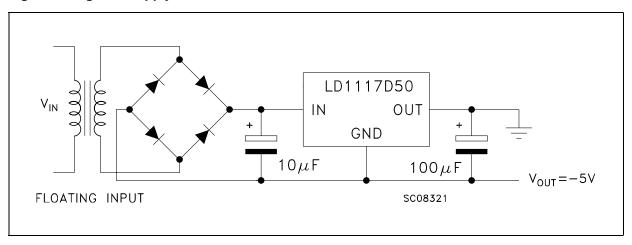


Figure 6: Active Terminator for SCSI-2 BUS

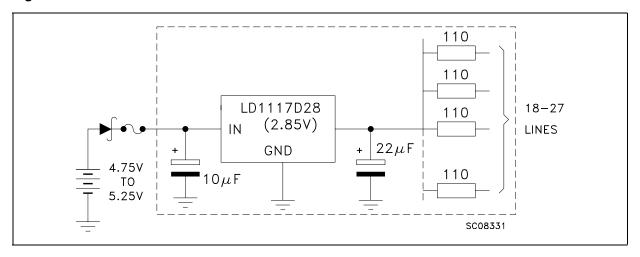


Figure 7: Circuit for Increasing Output Voltage

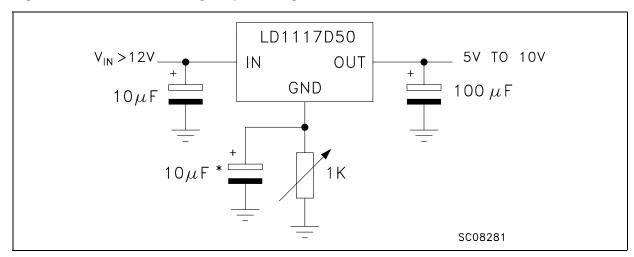
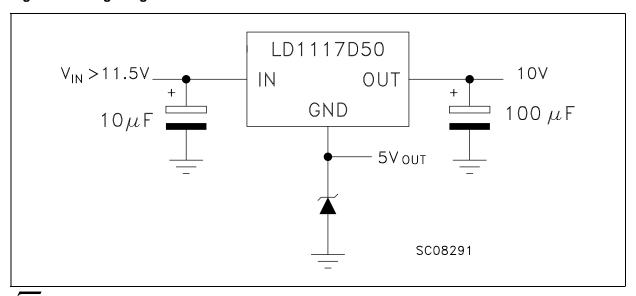
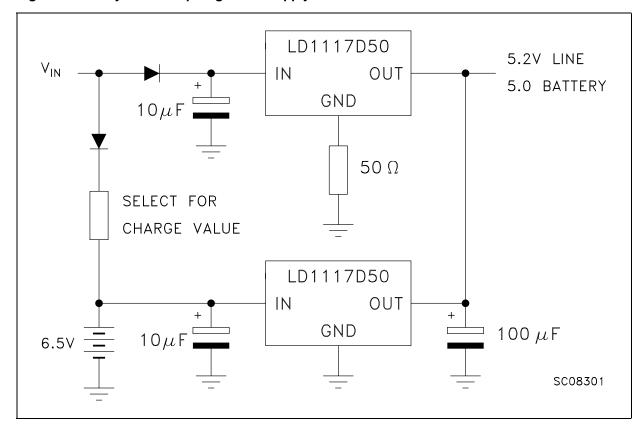


Figure 8: Voltage Regulator With Reference



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Figure 9: Battery Backed-up Regulated Supply



FEEDBACK PATH MUR410 3.3V OUTPUT (TYPICAL) ∎470μF LD1117D50 MUR410 +5V OUT IN 0.5A $10 \mu F$ **GND** 1N4002 $470 \mu F$ $+V_{IN}$ LD1117D50 MUR410 **SWITCHING** IN OUT REGULATOR $10\mu F$ **GND** 1N4002 $470 \mu F$ -5V0.5A SC08311

Figure 10: Post-Regulated Dual Supply

LD1117 ADJUSTABLE: APPLICATION NOTE

The LD1117 ADJUSTABLE has a thermal stabilized 1.25 \pm 0.012V reference voltage between the OUT and ADJ pins. I_{ADJ} is 60 μ A typ. (120 μ A max.) and Δ I_{ADJ} is 1 μ A typ. (5 μ A max.).

R1 is normally fixed to 120Ω . From figure 7 we obtain:

 $V_{OUT} = V_{REF} + R2 (I_{ADJ} + I_{R1}) = V_{REF} + R2 (I_{ADJ} + V_{REF}/R1) = V_{REF} (1 + R2/R1) + R2 x I_{ADJ}$. In normal application R2 value is in the range of few kohm, so the R2 x I_{DJ} product could not be considered in the V_{OUT} calculation; then the above expression becomes:

$$V_{OUT} = V_{RFF} (1 + R2 / R1).$$

In order to have the better load regulation it is important to realize a good Kelvin connection of R1 and R2 resistors. In particular R1 connection must be realized very close to OUT and ADJ pin, while R2 ground connection must be placed as near as possible to the negative Load pin. Ripple rejection can be improved by introducing a 10µF electrolytic capacitor placed in parallel to the R2 resistor (see Fig.8).

Figure 11: Adjustable Output Voltage Application

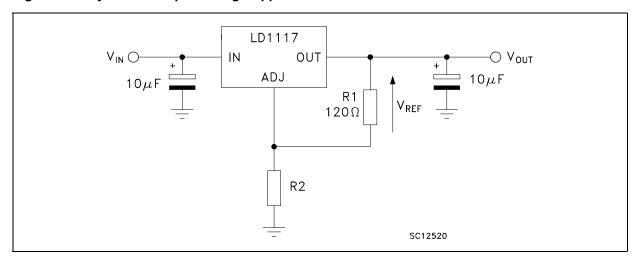
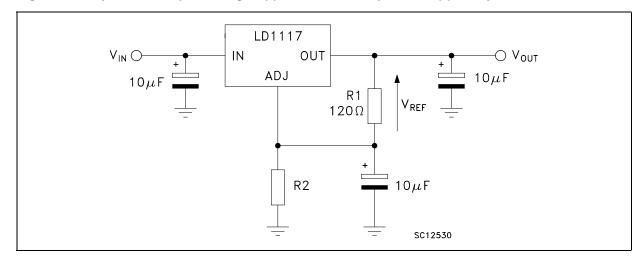


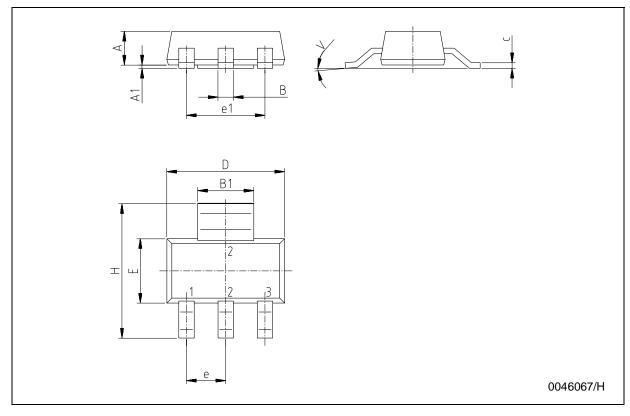
Figure 12: Adjustable Output Voltage Application with improved Ripple Rejection



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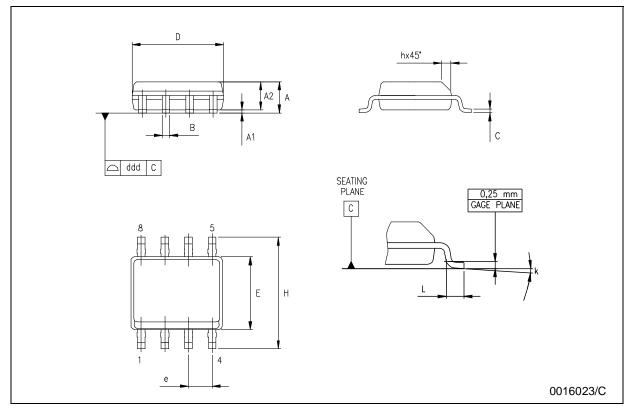
SOT-223 MECHANICAL DATA

DIM		mm.		mils			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А			1.8			70.9	
A1	0.02		0.1	0.8		3.9	
В	0.6	0.7	0.85	23.6	27.6	33.5	
B1	2.9	3	3.15	114.2	118.1	124.0	
С	0.24	0.26	0.35	9.4	10.2	13.8	
D	6.3	6.5	6.7	248.0	255.9	263.8	
е		2.3			90.6		
e1		4.6			181.1		
E	3.3	3.5	3.7	129.9	137.8	145.7	
Н	6.7	7	7.3	129.9	137.8	145.7	
V			10°			10°	



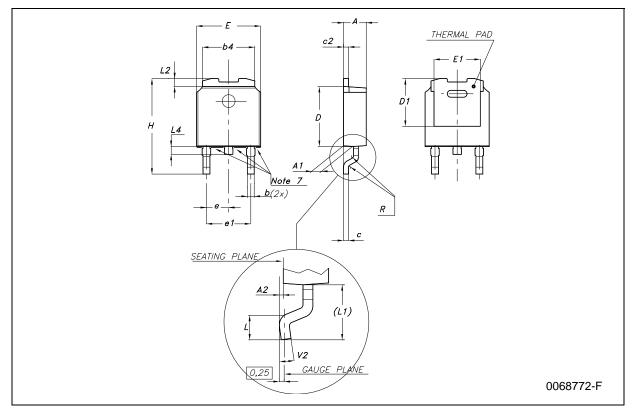
SO-8 MECHANICAL DATA

DIM.		mm.		inch				
DIWI.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
Α	1.35		1.75	0.053		0.069		
A1	0.10		0.25	0.04		0.010		
A2	1.10		1.65	0.043		0.065		
В	0.33		0.51	0.013		0.020		
С	0.19		0.25	0.007		0.010		
D	4.80		5.00	0.189		0.197		
Е	3.80		4.00	0.150		0.157		
е		1.27			0.050			
Н	5.80		6.20	0.228		0.244		
h	0.25		0.50	0.010		0.020		
L	0.40		1.27	0.016		0.050		
k		8° (max.)						
ddd			0.1			0.04		



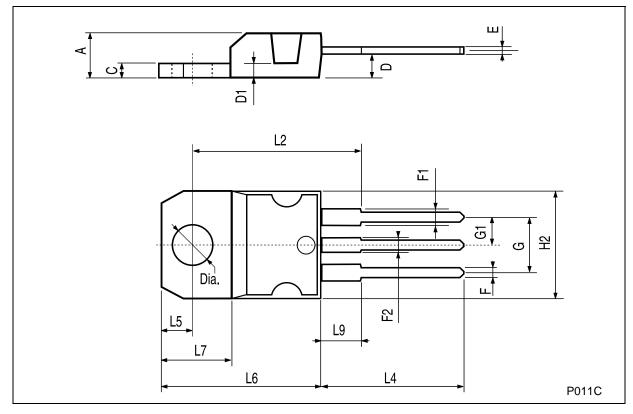
DPAK MECHANICAL DATA

DIM		mm.		inch			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А	2.2		2.4	0.086		0.094	
A1	0.9		1.1	0.035		0.043	
A2	0.03		0.23	0.001		0.009	
В	0.64		0.9	0.025		0.035	
B2	5.2		5.4	0.204		0.212	
С	0.45		0.6	0.017		0.023	
C2	0.48		0.6	0.019		0.023	
D	6		6.2	0.236		0.244	
D1		5.1			0.200		
E	6.4		6.6	0.252		0.260	
E1		4.7			0.185		
е		2.28			0.090		
e1	4.4		4.6	0.173		0.181	
Н	9.35		10.1	0.368		0.397	
L	1			0.039			
(L1)		2.8			0.110		
L2		0.8			0.031		
L4	0.6		1	0.023		0.039	



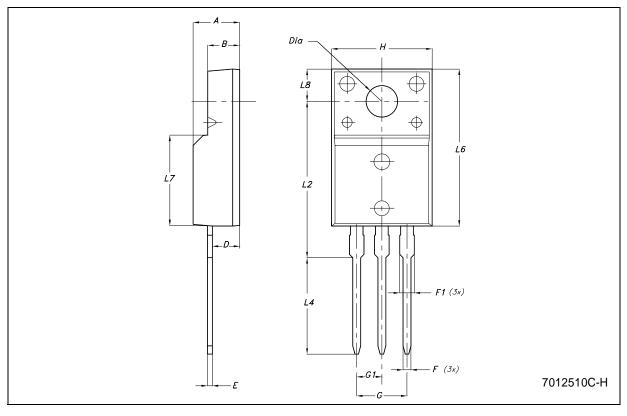
TO-220 MECHANICAL DATA

DIM		mm.			inch			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
Α	4.40		4.60	0.173		0.181		
С	1.23		1.32	0.048		0.051		
D	2.40		2.72	0.094		0.107		
D1		1.27			0.050			
Е	0.49		0.70	0.019		0.027		
F	0.61		0.88	0.024		0.034		
F1	1.14		1.70	0.044		0.067		
F2	1.14		1.70	0.044		0.067		
G	4.95		5.15	0.194		0.203		
G1	2.4		2.7	0.094		0.106		
H2	10.0		10.40	0.393		0.409		
L2		16.4			0.645			
L4	13.0		14.0	0.511		0.551		
L5	2.65		2.95	0.104		0.116		
L6	15.25		15.75	0.600		0.620		
L7	6.2		6.6	0.244		0.260		
L9	3.5		3.93	0.137		0.154		
DIA.	3.75		3.85	0.147		0.151		



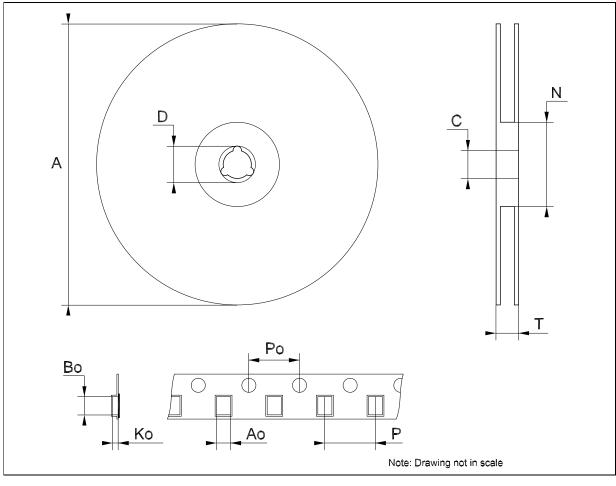
TO-220FM MECHANICAL DATA

DIM.		mm.		inch			
DIIVI.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А	4.50		4.90	0.177		0.193	
В	2.34		2.74	0.092		0.108	
D	2.56		2.96	0.101		0.117	
Е	0.45	0.50	0.60	0.018	0.020	0.024	
F	0.70		0.90	0.028		0.035	
F1			1.47			0.058	
G		5.08			0.200		
G1	2.34	2.54	2.74	0.092	0.100	0.108	
Н	9.96		10.36	0.392		0.408	
L2		15.8			0.622		
L4	9.45		10.05	0.372		0.396	
L6	15.67		16.07	0.617		0.633	
L7	8.99		9.39	0.354		0.370	
L8		3.30			0.130		
DIA.	3.08		3.28	0.121		0.129	



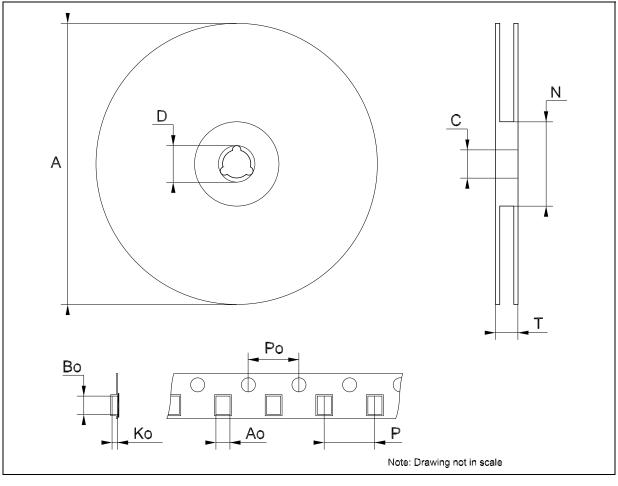
Tape & Reel SOT223 MECHANICAL DATA

DIM		mm.		inch			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А			330			12.992	
С	12.8	13.0	13.2	0.504	0.512	0.519	
D	20.2			0.795			
N	60			2.362			
Т			14.4			0.567	
Ao	6.73	6.83	6.93	0.265	0.269	0.273	
Во	7.32	7.42	7.52	0.288	0.292	0.296	
Ko	1.78		2	0.070		0.078	
Ро	3.9	4.0	4.1	0.153	0.157	0.161	
Р	7.9	8.0	8.1	0.311	0.315	0.319	



Tape & Reel SO-8 MECHANICAL DATA

mm.			inch		
MIN.	TYP	MAX.	MIN.	TYP.	MAX.
		330			12.992
12.8		13.2	0.504		0.519
20.2			0.795		
60			2.362		
		22.4			0.882
8.1		8.5	0.319		0.335
5.5		5.9	0.216		0.232
2.1		2.3	0.082		0.090
3.9		4.1	0.153		0.161
7.9		8.1	0.311		0.319
	12.8 20.2 60 8.1 5.5 2.1 3.9	MIN. TYP 12.8 20.2 60 8.1 5.5 2.1 3.9	MIN. TYP MAX. 330 12.8 13.2 20.2 60 22.4 8.1 8.5 5.9 2.1 2.3 3.9 4.1 4.1	MIN. TYP MAX. MIN. 330 12.8 13.2 0.504 20.2 0.795 0.795 60 2.362 8.1 8.5 0.319 5.5 5.9 0.216 2.1 2.3 0.082 3.9 4.1 0.153	MIN. TYP MAX. MIN. TYP. 330 12.8 13.2 0.504 20.2 0.795 0.795 60 2.362 0.319 8.1 8.5 0.319 5.5 5.9 0.216 2.1 2.3 0.082 3.9 4.1 0.153



Tape & Reel DPAK-PPAK MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А			330			12.992
С	12.8	13.0	13.2	0.504	0.512	0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	6.80	6.90	7.00	0.268	0.272	0.2.76
Во	10.40	10.50	10.60	0.409	0.413	0.417
Ko	2.55	2.65	2.75	0.100	0.104	0.105
Po	3.9	4.0	4.1	0.153	0.157	0.161
Р	7.9	8.0	8.1	0.311	0.315	0.319

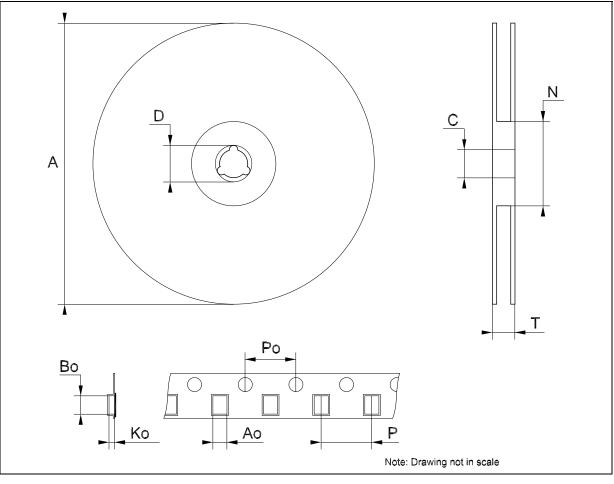


Table 19: Revision History

Date	Revision	Description of Changes
22-Sep-2004	15.0	Add new Part Number #12C; Typing Error: Note on table 2.
25-Oct-2004	16.0	Add V _{ref} Reference Voltage on Table 12.

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